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- Low Power Drain . . . 900 μW Typical With 5-V Supply
- Operates From ±15 V or From a Single Supply as Low as 3 V
- Output Drive Capability of 25 mA
- Emitter Output Can Swing Below Negative Supply
- Response Time . . . 1.2 µs Typ
- Low Input Currents: Offset Current ... 2 nA Typ Bias Current ... 15 nA Typ
- Wide Common-Mode Input Range: -14.5 V to 13.5 V Using ±15-V Supply
- Offset Balancing and Strobe Capability
- Same Pinout as LM211, LM311
- Designed To Be Interchangeable With Industry-Standard LP311

#### description/ordering information

The LP211 and LP311 devices are low-power versions of the industry-standard LM211 and LM311 devices. They take advantage of stable, high-value, ion-implanted resistors to perform the same function as the LM311 series, with a 30:1 reduction in power consumption, but only a 6:1 slowdown in response time. They are well suited for battery-powered applications and all other applications where fast response times are not needed. They operate over a wide range of supply voltages, from  $\pm 18$  V down to a single 3-V supply with less than 300- $\mu$ A current drain, but are still capable of driving a 25-mA load. The LP211 and LP311 are quite easy to apply free of oscillation if ordinary precautions are taken to minimize stray coupling from the output to either input or to the trim pins. In addition, offset balancing is available to minimize input offset voltage. Strobe capability also is provided to turn off the output (regardless of the inputs) by pulling the strobe pin low.

The LP211 is characterized for operation from –25°C to 85°C. The LP311 is characterized for operation from 0°C to 70°C.

| T <sub>A</sub> | V <sub>IO</sub> max<br>AT 25°C | PAC      | CKAGE <sup>†</sup> | ORDERABLE<br>PART NUMBER | TOP-SIDE<br>MARKING |
|----------------|--------------------------------|----------|--------------------|--------------------------|---------------------|
|                |                                | PDIP (P) | Tube of 50         | LP311P                   | LP311P              |
| –0°C to 70°C   | 7.5 mV                         | SOIC (D) | Tube of 75         | LP311D                   | 1 0011              |
|                |                                |          | Reel of 2500       | LP311DR                  | LP311               |
|                |                                | SOP (PS) | Reel of 2000       | LP311PSR                 | L311                |
| –25°C to 85°C  | 7.5 m)/                        |          | Tube of 75         | LP211D                   | 1 0011              |
|                | 7.5 mV                         | SOIC (D) | Reel of 2500       | LP211DR                  | LP211               |

#### ORDERING INFORMATION

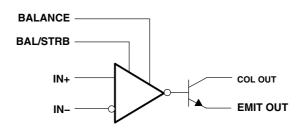
<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



| LP211 D PACKAGE<br>LP311 D, P, OR PS PACKAGE<br>(TOP VIEW) |   |   |                    |  |  |  |  |  |
|--|---|---|--------------------|--|--|--|--|--|
| EMIT OUT [   | 1 | 8 | ] V <sub>CC+</sub> |  |  |  |  |  |
| IN+ [  | 2 | 7 | ] COL OUT          |  |  |  |  |  |
| IN- [  | 3 | 6 | ] BAL/STRB         |  |  |  |  |  |
| V <sub>CC-</sub> [   | 4 | 5 | ] BALANCE          |  |  |  |  |  |

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#### functional block diagram



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

| Supply voltage (see Note 1): V <sub>CC+</sub>                   |            |                  |
|---|------------|------------------|
|   |            |                  |
| Differential input voltage, VID (see Note 2)                    |            | ±30 V            |
| Input voltage, V <sub>I</sub> (either input, see Notes 1 and 3) |            | ±15 V            |
| Voltage from emitter output to V <sub>CC</sub>                  |            | 30 V             |
| Voltage from collector output to V <sub>CC</sub>                |            | 40 V             |
| Voltage from collector output to emitter output                 |            | 40 V             |
| Duration of output short circuit (see Note 4)                   |            | 40 V             |
| Package thermal impedance, $\theta_{JA}$ (see Notes 5 and 6):   | D package  | 97°C/W           |
|   | P package  | 85°C/W           |
|   | PS package | 95°C/W           |
| Operating virtual junction temperature, T <sub>J</sub>          |            | 150°C            |
| Storage temperature range, T <sub>stg</sub>                     |            | . −65°C to 150°C |

<sup>†</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the recommended operating conditions section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V<sub>CC+</sub> and V<sub>CC-</sub>.

- 2. Differential input voltages are at IN+ with respect to IN-.
- 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage of ±15 V, whichever is less.
- 4. The output may be shorted to ground or to either power supply.
- 5. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
- 6. The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions

|                                  |                | MIN                    | МАХ                    | UNIT |
|----------------------------------|----------------|------------------------|------------------------|------|
| $( V_{CC\pm}  \le 15 \text{ V})$ | Input voltage  | V <sub>CC-</sub> + 0.5 | V <sub>CC+</sub> – 1.5 | V    |
| $V_{CC+} - V_{CC-}$              | Supply voltage | 3.5                    | 30                     | V    |



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| PARAMETER                           |   | TEST CO   | TEST CONDITIONS                              |            |    | TYP <sup>†</sup> | MAX   | UNIT |  |
|-------------------------------------|---|---|--|------------|----|------------------|-------|------|--|
| .,                                  |   | <b>D0</b> 400 kg                                      | 0 11   | 25°C       |    | 2                | 7.5   |      |  |
| VID                                 | Input offset voltage                            | RS < 100 kΩ,  | See Note 7                                   | Full range |    |                  | 10    | mV   |  |
|                                     |   | V <sub>ID</sub> < -10 mV,<br>See Note 8               | l <sub>OL</sub> = 25 mA,                     | 25°C       |    | 0.4              | 1.5   |      |  |
| V <sub>OL</sub> Low-level output vo | Low-level output voltage                        | $V_{CC} = 4.5 V,$<br>$V_{ID} < -10 mV,$<br>See Note 8 | $V_{CC-} = 0,$<br>$I_{OL} = 1.6 \text{ mA},$ | Full range |    | 0.1              | 0.4   | V    |  |
|                                     | land affect and an end                          | Care Note 7   |  | 25°C       |    | 2                | 25    |      |  |
| l <sub>IO</sub>                     | Input offset current                            | See Note 7  |  | Full range |    |                  | 35    | nA   |  |
|                                     |   |   |  | 25°C       |    | 15               | 100   |      |  |
| I <sub>IB</sub>                     | Input bias current                              |   |  | Full range |    |                  | 150   | nA   |  |
|                                     | Low-level strobe current                        | V <sub>(strobe)</sub> = 0.3 V,<br>See Note 9          | V <sub>ID</sub> < -10 mV,                    | 25°C       |    | 100              | 300   | μA   |  |
| I <sub>O(off)</sub>                 | Output off-state current                        | V <sub>ID</sub> > 10 mV,                              | V <sub>CE</sub> = 35 V                       | 25°C       |    | 0.2              | 100   | nA   |  |
| A <sub>VD</sub>                     | Large-signal differential-voltage amplification | $R_L = 5 k\Omega$                                     |  | 25°C       | 40 | 100              |       | V/mV |  |
| I <sub>CC+</sub>                    | Supply current from V <sub>CC+</sub>            | $V_{ID} = -50 \text{ mV},$                            | R <sub>L</sub> = ∞                           | Full range |    | 150              | 300   | μA   |  |
| I <sub>CC-</sub>                    | Supply current from V <sub>CC</sub>             | V <sub>ID</sub> = 50 mV,                              | R <sub>L</sub> = ∞                           | Full range |    | - 80             | - 180 | μA   |  |

#### electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

<sup>†</sup> All typical values are at  $V_{CC\pm} = \pm 15$  V,  $T_A = 25^{\circ}C$ .

NOTES: 7. The offset voltages and offset currents given are the maximum values required to drive the output within 1 V of either supply with a 1-mA load. Thus, these parameters define an error band and take into account the worst-case effects of voltage gain and input impedance.

8. Voltages are with respect to EMIT OUT and  $V_{\text{CC}-}$  tied together.

9. The strobe should not be shorted to ground; it should be current driven at 100  $\mu$ A to 300  $\mu$ A.

### switching characteristics, V<sub>CC $\pm$ </sub> = $\pm$ 5 V, T<sub>A</sub> = 25°C (unless otherwise noted)

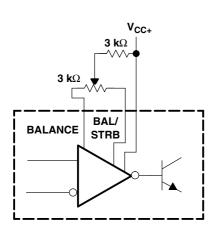
| PARAMETER     | TEST CONDITIONS | TYP | UNIT |
|---------------|-----------------|-----|------|
| Response time | See Note 10     | 1.2 | μs   |

NOTE 10: The response time is specified for a 100-mV input step with 5-mV overdrive.



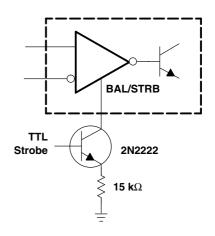
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### **TYPICAL APPLICATION CIRCUIT**

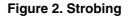


NOTE: If offset balancing is not used, the BALANCE and BAL/STRB pins should be shorted together.

Figure 1. Offset Balancing



NOTE: Do not connect strobe pin directly to ground, because the output is turned off whenever current is pulled from the strobe pin.







10-Jun-2014

### PACKAGING INFORMATION

| Orderable De | vice Status | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|--------------|-------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|--------------------|--------------|-------------------------|---------|
| LP211D       | ACTIVE      | SOIC         | D                  | 8    | 75             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | -25 to 85    | LP211                   | Samples |
| LP211DG4     | ACTIVE      | SOIC         | D                  | 8    | 75             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | -25 to 85    | LP211                   | Samples |
| LP211DR      | ACTIVE      | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | -25 to 85    | LP211                   | Samples |
| LP211DRE     | 4 ACTIVE    | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | -25 to 85    | LP211                   | Samples |
| LP211DRG     | 4 ACTIVE    | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | -25 to 85    | LP211                   | Samples |
| LP211P       | OBSOLET     | E PDIP       | Р                  | 8    |                | TBD                        | Call TI                 | Call TI            | -25 to 85    |                         |         |
| LP311D       | ACTIVE      | SOIC         | D                  | 8    | 75             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | 0 to 70      | LP311                   | Samples |
| LP311DG4     | ACTIVE      | SOIC         | D                  | 8    | 75             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | 0 to 70      | LP311                   | Samples |
| LP311DR      | ACTIVE      | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | 0 to 70      | LP311                   | Samples |
| LP311DRG     | 4 ACTIVE    | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM | 0 to 70      | LP311                   | Samples |
| LP311P       | ACTIVE      | PDIP         | Ρ                  | 8    | 50             | Pb-Free<br>(RoHS)          | CU NIPDAU               | N / A for Pkg Type | 0 to 70      | LP311P                  | Samples |
| LP311PE4     | ACTIVE      | PDIP         | Ρ                  | 8    | 50             | Pb-Free<br>(RoHS)          | CU NIPDAU               | N / A for Pkg Type | 0 to 70      | LP311P                  | Samples |
| LP311PWL     | E OBSOLET   | E TSSOP      | PW                 | 8    |                | TBD                        | Call TI                 | Call TI            | 0 to 70      |                         |         |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.



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Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and package die adhesive used between the die adhesive

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nor | ninal           |                    |   |      |                          |                          |            |            |            |            |           |                  |
|-------------------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device                  | Package<br>Type | Package<br>Drawing |   | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
| LP211DR                 | SOIC            | D                  | 8 | 2500 | 330.0                    | 12.4                     | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |
| LP311DR                 | SOIC            | D                  | 8 | 2500 | 330.0                    | 12.4                     | 6.4        | 5.2        | 2.1        | 8.0        | 12.0      | Q1               |

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# PACKAGE MATERIALS INFORMATION

26-Jan-2013



\*All dimensions are nominal

| Device  | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------|--------------|-----------------|------|------|-------------|------------|-------------|
| LP211DR | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |
| LP311DR | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |

P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



# **PW0008A**



# **PACKAGE OUTLINE**

### TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153, variation AA.



# PW0008A

# **EXAMPLE BOARD LAYOUT**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# PW0008A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

9. Board assembly site may have different recommendations for stencil design.



<sup>8.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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| RFID                         | www.ti-rfid.com          |                               |                                   |
| OMAP Applications Processors | www.ti.com/omap          | TI E2E Community              | e2e.ti.com                        |
| Wireless Connectivity        | www.ti.com/wirelessconne | ctivity                       |                                   |

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